

T498X685K050ATE500

T498, Tantalum, MnO2 Tantalum, High Temperature, 6.8 uF, 10%, 50 VDC, SMD, MnO2, Molded, Hi-Temp, 150C, Auto, AEC-Q200, N/A, 500 mOhms, 7343, 4.3 mm, 1.3 mm



General Information	
Series	T498
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Hi-Temp, 150C, Auto, AEC-Q200
Features	Automotive, 150C
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Typical Component Weight	652.04 mg
Shelf Life	156 Weeks
MSL	1

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	4mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	1.7mm REF
R	1mm REF
Х	0.1mm +/-0.1mm REF

Specifications	
Capacitance	6.8 uF
Tolerance	10%
Voltage DC	50 VDC (85C), 40 VDC (125C), 33.5 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5% 120Hz 25C
Failure Rate	N/A
ESR	500 mOhms (100kHz 25C)
Ripple Current	574 mA (rms, 100kHz 25C), 516.6 mA (rms, 85C), 172.2 mA (rms, 150C)
Leakage Current	3.4 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

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